

# Spin-valley coupling induce Spin Hall Effect in Graphene/Transition Metal Dichalcogenide heterostructures

Jose H. Garcia

C. K. Safeer, Josep Ingla-Aynés, Franz Herling, **Jose H. Garcia**, Marc Vila, Nerea Ontoso, M. Reyes Calvo, Stephan Roche, Luis E. Hueso, and Fèlix Casanova.

CIC nanoGUNE, 20018 Donostia-San Sebastian, Basque Country, Catalan Institute of Nanoscience and Nanotechnology (ICN2), CSIC, The Barcelona Institute of Science and Technology, Universitat Autònoma de Barcelona, IKERBASQUE, Basque Foundation for Science, and ICREA – Institució Catalana de Recerca i Estudis Avançats,, Spain.

[josehugo.garcia@icn2.cat](mailto:josehugo.garcia@icn2.cat)

Spintronics, a field which aims at using the electron's spin for ultra-fast low-power electronic devices, has been limited by low spin relaxation times and by the absence of a reliable spin current source. A large spin-to-charge conversion is necessary for obtaining spintronic devices operating at low currents, and it is, therefore, necessary for power efficiency and for departing from charge-based logic and memories. In recent months, we measured a new source of spin current at room temperature, the spin Hall effect in Graphene/MoS2 heterostructure [1]. We expect that the spin Hall effect, combined with other unique phenomena of these heterostructures such as the spin lifetime anisotropy[2], could be used as a platform for solving some of the current spintronics challenges.

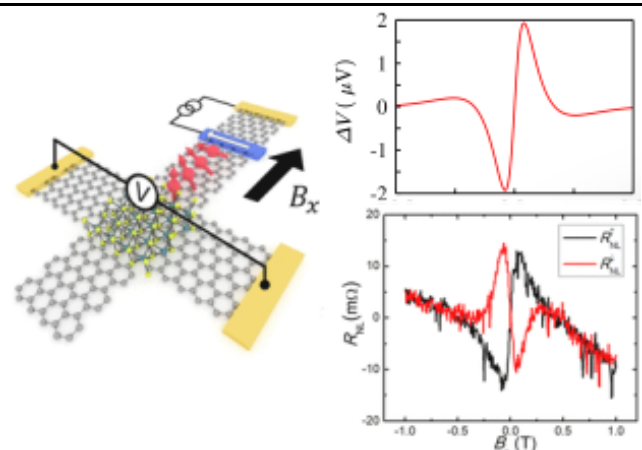
In this work, we developed a theory for explaining the spin Hall effect and the Rashba-Edelstein effect[3-4] in Graphene/MoS2 heterostructure. We compare this theory with a fully quantum mechanic calculation of the spin Hall conductivity and of the non-equilibrium spin density, computed through the Kubo Formula in a system consisting of millions of

orbitals. We showed that predictions obtained previously can be explained within the framework of a valley-dependent spin Hall effect, which originates from an unique combination of spin-valley coupling and staggered potential present in these heterostructures. The effect of vacancies and other sources of local spin-orbit coupling will be briefly discussed, and perspective for future research will be also presented.

## References

- [1] C. K. Safeer, Josep Ingla-Aynés, Franz Herling, Jose H. Garcia, Marc Vila, Nerea Ontoso, M. Reyes Calvo, Stephan Roche, Luis E. Hueso, and Fèlix Casanova, *Nano Lett.*, 19 (2019).
- [2] Jose H. Garcia, Marc Vila, Aron W. Cummings and Stephan Roche, *Chem. Soc. Rev.*, 47, (2018).
- [3] Jose H. Garcia, Aron W. Cummings, and Stephan Roche, *Nano Lett.*, 17, (2017).
- [4] Manuel Offidani, Mirco Millettari, Roberto Raimondi, *Phys. Rev. Lett.*, 119 (Ye2017).

## Figures



**Figure 1:** (Left) Experimental setup for measuring the Spin Hall effect. (Right) The predicted (Top) and measured (Bottom) signal.